



PNP PRE-BIASED TRANSISTOR IN SOT323

Features

- Epitaxial Planar Die Construction
- · Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Part Number	R1(NOM)	R2(NOM)
DDTB113EU	1kΩ	1kΩ
DDTB123EU	2.2kΩ	2.2kΩ
DDTB143EU	4.7kΩ	4.7kΩ
DDTB114EU	10kΩ	10kΩ
DDTB122JU	0.22kΩ	4.7kΩ
DDTB113ZU	1kΩ	10kΩ
DDTB123YU	2.2kΩ	10kΩ
DDTB133HU	3.3kΩ	10kΩ
DDTB123TU	2.2kΩ	Open
DDTB143TU	4.7kΩ	Open
DDTB114TU	10kΩ	Open
DDTB114GU	0	10kΩ

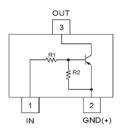
SOT323



Top View

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)



Device Schematic

Ordering Information (Note 4)

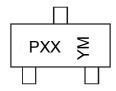
Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DDTB113EU-7-F	Obsolete	Standard	P60	7	8	3,000
DDTB123EU-7-F	Obsolete	Standard	P61	7	8	3,000
DDTB143EU-7-F	Active	Standard	P62	7	8	3,000
DDTB114EU-7-F	Obsolete	Standard	P63	7	8	3,000
DDTB122JU-7-F	Obsolete	Standard	P64	7	8	3,000
DDTB113ZU-7-F	Obsolete	Standard	P65	7	8	3,000
DDTB123YU-7-F	Obsolete	Standard	P66	7	8	3,000
DDTB133HU-7-F	Obsolete	Standard	P67	7	8	3,000
DDTB123TU-7-F	Obsolete	Standard	P69	7	8	3,000
DDTB143TU-7-F	Obsolete	Standard	P70	7	8	3,000
DDTB114TU-7-F	Obsolete	Standard	P71	7	8	3,000
DDTB114GU-7-F	Obsolete	Standard	P72	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information



PXX = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Date Code Hoj												
Year	2016		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	D		ı	J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	;	Symbol	Value	Unit
Supply Voltage, (3) to (2)		Vcc	50	V
Input Voltage, (1) to (2)	DDTB113EU DDTB123EU DDTB143EU DDTB114EU DDTB122JU DDTB113ZU DDTB123YU DDTB133HU	Vin	+10 to -10 +10 to -12 +10 to -30 +10 to -40 +5 to -5 +5 to -10 +5 to -12 +6 to -20	V
Input Voltage, (2) to (1)	DDTB123TU DDTB143TU DDTB114TU DDTB114GU	VEBO (MAX)	-5	V
Output Current	All	Ic	-500	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. Mounted on FR4 PC Board with minimum recommended pad layout.



Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.) R1, R2 Types

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Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DDTB113EU DDTB123EU DDTB143EU DDTB114EU DDTB122JU DDTB113ZU DDTB123YU DDTB133HU	V _{I(off)}	-0.5 -0.5 -0.5 -0.5 -0.5 -0.3 -0.3	_	_	V	V_{CC} = -5V, I_{O} = -100 μ A
Input Voltage	DDTB113EU DDTB123EU DDTB143EU DDTB114EU DDTB122JU DDTB113ZU DDTB123YU DDTB133HU	$V_{I(on)}$	1	_	-3.0 -3.0 -3.0 -3.0 -3.0 -2.0 -2.0 -2.0		V_{O} = -0.3V, I_{O} = -20mA V_{O} = -0.3V, I_{O} = -20mA V_{O} = -0.3V, I_{O} = -20mA V_{O} = -0.3V, I_{O} = -10mA V_{O} = -0.3V, I_{O} = -30mA V_{O} = -0.3V, I_{O} = -20mA V_{O} = -0.3V, I_{O} = -20mA V_{O} = -0.3V, I_{O} = -20mA
Output Voltage		$V_{O(on)}$		—	-0.3	V	$I_{O}/I_{I} = -50 \text{mA}/-2.5 \text{mA}$
Input Current	DDTB113EU DDTB123EU DDTB143EU DDTB114EU DDTB122JU DDTB113ZU DDTB123YU DDTB133HU	lı		_	-7.2 -3.8 -1.8 -0.88 -28 -7.2 -3.6 -2.4	mA	V _I = -5V
Output Current		I _{O(off)}	_	_	-0.5	μА	$V_{CC} = -50V, V_{I} = 0V$
DC Current Gain	DDTB113EU DDTB123EU DDTB143EU DDTB114EU DDTB122JU DDTB113ZU DDTB123YU DDTB133HU	Gı	33 39 47 56 47 56 56 56	_	_	_	V _O = 5V, I _O = 50mA
Gain-Bandwidth Product (Note 6)		f_{T}		200	_	MHz	$V_{CE} = -10V$, $I_{E} = -5mA$, $f = 100MHz$

Electrical Characteristics @ T_A = 25°C unless otherwise specified R1-Only, R2-Only Types

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CBO}	-50	_	_	V	I _C = -50μA
Collector-Emitter Breakdown Voltage		BV_{CEO}	-40	_	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	DDTB123TU DDTB143TU DDTB114TU DDTB114GU	BV_EBO	-5			٧	I _E = -50μA I _E = -50μA I _E = -50μA I _E = -720μA
Collector Cutoff Current		I _{CBO}	_		-0.5	μА	V _{CB} = -50V
Emitter Cutoff Current	DDTB123TU DDTB143TU DDTB114TU DDTB114GU	I _{EBO}		_	-0.5 -0.5 -0.5 -580	μА	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}		_	-0.3	V	I_C = -50mA, I_B = -2.5mA
DC Current Transfer Ratio	DDTB123TU DDTB143TU DDTB114TU DDTB114GU	h _{FE}	100 100 100 56	250 250 250 —	600 600 600	_	I _C = -5mA, V _{CE} = -5V
Gain-Bandwidth Product (Note 6)		f⊤	_	200	_	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

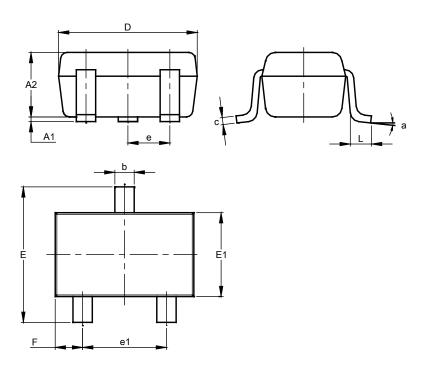
Note: 6. Transistor - for reference only



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

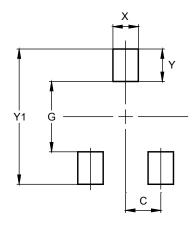


SOT323							
Dim	Min Max Typ						
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
С	0.10	0.18	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C	.650 B	SC				
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All	Dimen	sions	in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



Dimensions	Value
Dillielisions	(in mm)
С	0.650
G	1.300
X	0.470
Y	0.600
Y1	2.500



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